NSN 5962-01-123-7996

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-123-7996
Body Length:
1.260 inches
Body Width:
Between 0.350 inches and 0.390 inches
Body Height:
Between 0.150 inches and 0.210 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and positive outputs and w/enable
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
15 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.5 volts power source
Time Rating Per Chacteristic:
800.00 nanoseconds propagation delay time, low to high level output and 800.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Ram
Test Data Document:
08748-u-14 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
22 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

Fiig: A458a0

Yes - demil/mli